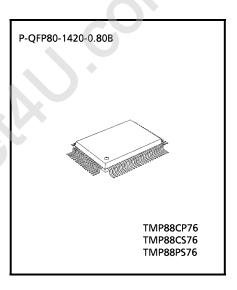
CMOS 8-Bit Microcontroller

#### TMP88PS76F

The TMP88PS76 are the high-speed and high performance 8-bit single chip microcomputers which built in a program storage area (64 Kbyte) and the One-Time PROM of bector table storage area (256 byte). The TMP88PS76 is pin compatible with the TMP88CP76/S76. The operations possible with the TMP88PS76 can be performed by writing programs to PROM. The TMP88PS76 can write and verify in the same way as the TC571000 an EPROM programmer.

Part No.	Part No. OTP		Package	Adaptor Socket	
TMP88PS76F	64 Kbyte + 256 byte	2 Kbyte	P-QFP80-1420-0.80B	BM11157	



and conditions set forth in the IOSHIBA Semiconductor Reliability Handbook.

The products described in this document are subject to the foreign exchange and foreign trade laws.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

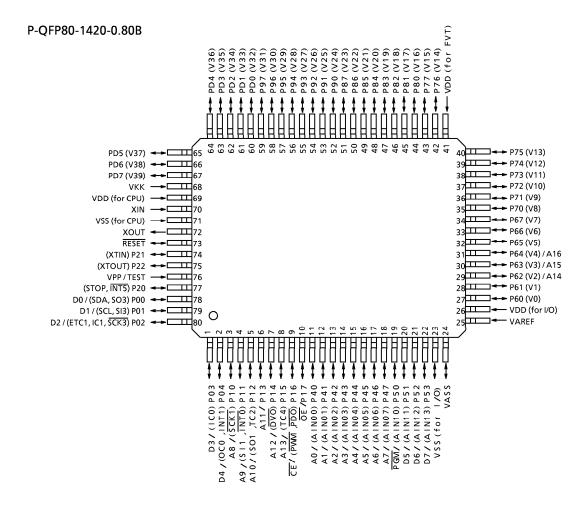
The information contained herein is subject to change without notice.

3-76-129 1999-12-14

For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance/Handling Precautions.

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handhook and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

## Pin Assignments (Top View)



#### **Pin Function**

The TMP88PS76 has two modes: MCU and PROM.

(1) MCU mode
In this mode, the TMP88PS76 is pin compatible with the TMP88CP76/S76 (fix the TEST pin at low level).

#### (2) PROM mode

Pin Name (PROM mode)	Input/Output	Functions	Pin Name (MCU mode)			
A16			P64			
A15 to A8	Input	PROM address inputs	P63, P62, P15 to P10			
A7 to A0			P47 to P40			
D7 to D0	I/O	PROM data input/outputs	P53 to P51, P04 to P00			
CE		Chip enable signal input (active low)	P16			
ŌĒ	Input	Output enable signal input (active low)	P17			
PGM		Program mode single input	P50			
VPP		+ 12.75 V / 5 V (Program supply voltage)	TEST			
vcc	Power supply	+ 6.25 V / 5 V	VDD			
GND		0 V	VSS			
P07 to P05		Pull-up with resistance for input processing				
P60		PROM mode setting pin. Be fixed at high level.				
P21	Input	PRODUTINOUS SELLING DITE. BE TIXED AT HIGH TEVEL.				
P67, P66, P61		PROM mode setting pin. Be fixed at low level.	evel			
RESET		The in mode secting pine be tixed delete level.				
P65						
P77 to P70						
P87 to P80	Output	Open				
P97 to P90						
PD7 to PD0						
XIN	Input	Connect an 8 MHz oscillator to stabilize the interna	al state			
XOUT	Output	Commercian of white Costabilize the liftering	ui state.			
VAREF		OV (GND)				
VASS	Power supply	0 V (GND)				
VKK		Open				

#### **Operational Description**

The configuration and functions of the TMP88PS76 are the same as those of the TMP88CP76/S76, except in that a one-time PROM is used instead of an on-chip mask ROM.

#### 1. Operating Mode

The TMP88PS76 has two modes: MCU and PROM.

#### 1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level. In the MCU mode, operation is the same as with the TMP88CP76/S76 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

#### 1.1.1 Program memory

The TMP88PS76 has a 64 Kbyte (addresses  $04000_H$  to  $13FFF_H$  in the MCU mode, addresses  $00000_H$  to  $0FFFF_H$  in the PROM mode) of program storage area and 256 byte (addresses FFF00 to  $FFFFF_H$  in the MCU mode, addresses 1FF00 to  $1FFFF_H$  in the PROM mode) one-time PROM of vector table storage area.

3-76-132 1999-12-14

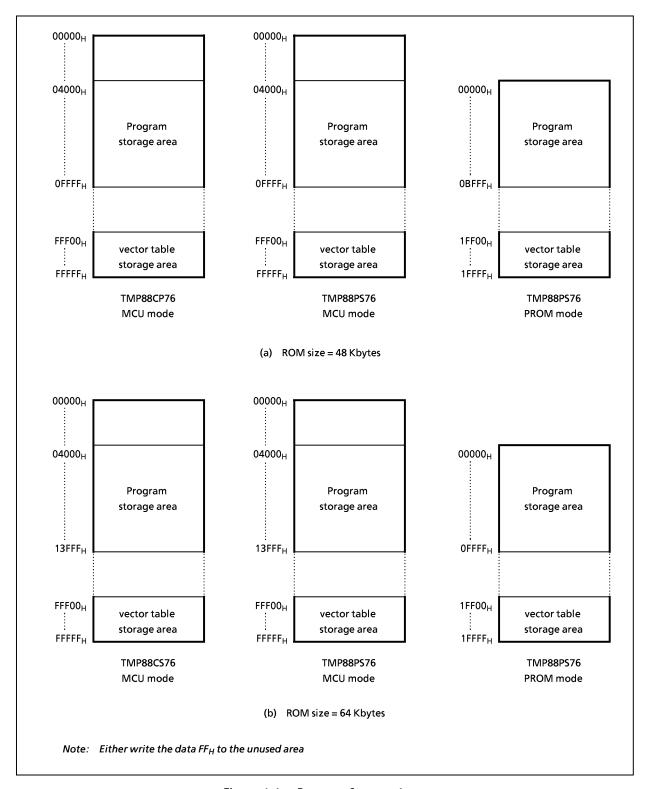


Figure 1-1. Program Storage Area

#### 1.1.2 Data memory

The TMP88PS76 has an on-chip 2 Kbyte data memory (static RAM).

# 1.1.3 Input/output circuitry

#### (1) Control pins

The control pins of the TMP88PS76 are the same as those of the TMP88CP76/S76 except that the TEST pin has is no built-in pull-down resistance.

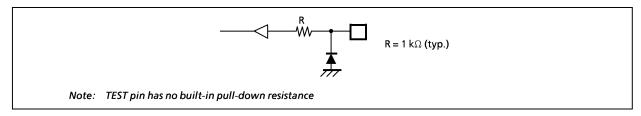


Figure 1-2. TEST Pin

### (2) I/O ports

The I/O circuitries of TMP88PS76 I/O ports are the same as the TMP88CP76/S76.

## 1.2 PROM Mode

The PROM mode is activated by setting shown in Figure 1-2. The PROM mode is used to write and verify programs with a general-purpose PROM programmer. The high-speed programming mode can be used for program operation.

The TMP88PS76 is not supported an electric signature mode, so the ROM type must be set to TC571000. Set the adaptor socket switch to "N".

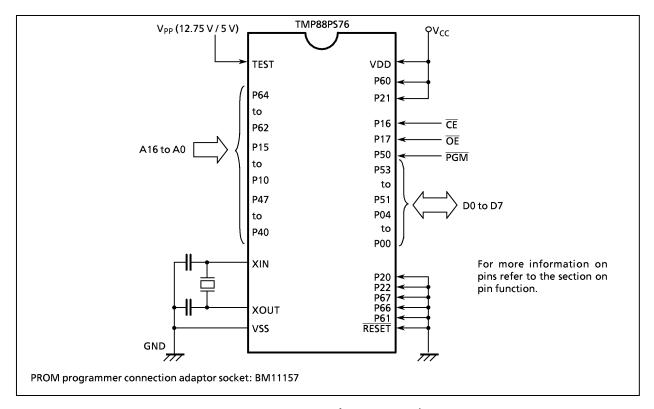


Figure 1-3. Setting for PROM Mode

## 1.2.1 Programming flowchart (High-speed programming)

The high-speed programming mode is achieved by applying the program voltage (  $\pm$  12.75 V) to the Vpp pin when Vcc = 6.25 V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the  $\overline{\text{CE}}$  input. The programmed data is verified. If incorrect, another 0.1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5 V.

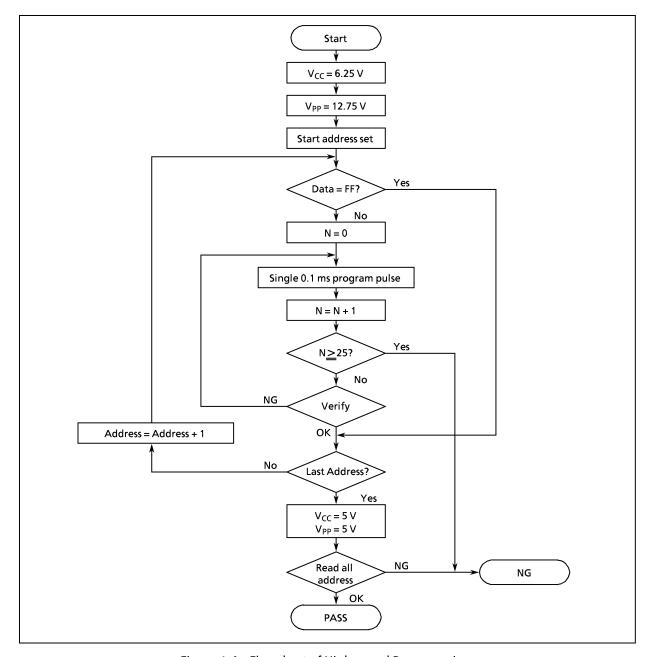


Figure 1-4. Flowchart of High-speed Programming

#### 1.2.2 Writing method for general-purpose PROM program

(1) Adapters BM11157

(2) Adapter setting Switch (SW1) is set to side N.

(3) PROM programmer specifying

i) PROM type is specified to TC571000.
 Writing voltage: 12.75 V (high-speed program)

ii) Data transfer (copy) (Note 1)

In TMP88PS76, EPROM is within the addresses  $00000_H$  to  $0FFFF_H$  and  $1FF00_H$  to  $1FFFF_H$ . Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.

Program area: transferred addresses 04000<sub>H</sub> to 13FFF<sub>H</sub> to addresses 00000 to 0FFFF<sub>H</sub>

Vector area: transferred addresses FFF00<sub>H</sub> to FFFFF<sub>H</sub> to 1FF00 to 1FFFF<sub>H</sub>

iii) Writing address is specified. (Note 1)

Start address: 00000<sub>H</sub> End address: 1FFFF<sub>H</sub>

(4) Writing

Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

- Note 1: The specifying method is referred to the PROM programmer description. Either write the data  $FF_H$  to the unused area or set the PROM programmer to access only the program storage area.
- Note 2: When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reversed, MCU, the adapter and PROM program is damaged.
- Note 3: The TMP88PS76 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying  $12 \ V \pm 0.5 \ V$  to the address pin 9 (A9). The signature must not be used.

#### **Electrical Characteristics**

**Absolute Maximum Ratings** 

 $(V_{SS} = 0 V)$ 

Parameter	Symbol	Pins	Ratings	Unit
Supply Voltage	$V_{DD}$		- 0.3 to 6.5	V
Program Voltage	$V_{PP}$	TEST/VPP	- 0.3 to 13.0	٧
logut Valtaga	V <sub>IN1</sub>	P1, P2, P4, P5, XOUT, RESET	- 0.3 to V <sub>DD</sub> + 0.3	V
Input Voltage	V <sub>IN2</sub>	P0 port	– 0.3 to 5.5 V	V
	V <sub>OUT1</sub>	P1, P2, P4, P5, XOUT, RESET	- 0.3 to V <sub>DD</sub> + 0.3	
Output Voltage	V <sub>OUT2</sub>	P0 port	– 0.3 to 5.5 V	V
	V <sub>OUT3</sub>	Source open drain ports	$V_{DD} - 40 \text{ to } V_{DD} + 0.3$	
	I <sub>OUT1</sub>	P0, P1, P2, P4, P5 ports	3.2	
Output Current (Per 1 pin)	I <sub>OUT2</sub>	P6, P7, P80, 81 Ports	<b>– 25</b>	mA
	I <sub>OUT3</sub>	P82 to P87, P9, PD ports	- 12	
	$\Sigma$ I <sub>OUT1</sub>	P1, P4, P5 ports	- 40	
Output Current (Total)	$\Sigma$ I <sub>OUT2</sub>	P0, P1, P2, P4, P5 ports	60	mA
	Σ I <sub>OUT3</sub>	P6, P7, P8, P9, PD ports	- 120	
Power Dissipation [Topr = 25°C]	PD	Note2	1200	mW
Soldering Temperature (time)	Tsld		260 (10 s)	°C
Storage Temperature	Tstg		- 55 to 125	°C
Operating Temperature	Topr		-30 to 70	°C

Note 1: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Note 2: Power Dissipation (PD); For PD, it is necessary to decrease -14.3 mW/°C. (Refernce to TMP88CP76/S76)

Recommended Operating Conditions

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Pins	(	Conditions	Min	Max	Unit
			fc =	NORMAL 1, 2 modes			
			12.5 MHz	IDLE1, 2 modes			
Supply Voltage	V <sub>DD</sub>		fs =	SLOW mode	4.5	5.5	V
			32.768 kHz	SLEEP mode			
				STOP mode	2.0		
	V <sub>IH1</sub>	Except hysteresis input	$V_{DD} \ge 4.5 V$ $V_{DD} < 4.5 V$		V <sub>DD</sub> × 0.70		
Input High Voltage	V <sub>IH2</sub>	Hysteresis input			V <sub>DD</sub> × 0.75	V <sub>DD</sub>	V
Imput riigh voitage	V <sub>IH3</sub>				$V_{DD} \times 0.90$		
	V <sub>IL1</sub>	Except hysteresis input				$V_{DD} \times 0.30$	
Input Low Voltage	V <sub>IL2</sub>	Hysteresis input	$V_{DD} \ge 4.5 V$			V <sub>DD</sub> × 0.25	V
	V <sub>IL3</sub>		V <sub>DD</sub> < 4.5 V			V <sub>DD</sub> × 0.10	
Clask Francisco	fc	XIN, XOUT	V <sub>DD</sub>	= 4.5 V to 5.5 V	1.0	12.5	MHz
Clock Frequency	fs	XTIN, XTOUT	V <sub>DD</sub>	= 2.7 V to 5.5 V	30.0	34.0	kHz

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

D.C. Characteristics

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Pins	Conditions	Min	Тур.	Max	Unit
Hysteresis Voltage	V <sub>H\$</sub>	Hysteresis input		-	0.9	-	V
Input Current	I <sub>IN1</sub> I <sub>IN2</sub>	TEST Open drain ports, Tri-state ports RESET, STOP	V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.5 V / 0 V	-	-	± 2	μΑ
Input Resistance	R <sub>IN3</sub>	RESET		100	220	450	
Pull-down Resistance	R <sub>K</sub>	Source open drain ports	$V_{DD} = 5.5 \text{ V}, V_{KK} = -30 \text{ V}$	50	80	110	kΩ
	I <sub>LO1</sub>	Sink open drain ports	V <sub>DD</sub> = 5.5 V, V <sub>OUT</sub> = 5.5 V	_	_	2	
Output Leakage	I <sub>LO2</sub>	Source open drain ports	$V_{DD} = 5.5 \text{ V}, \ V_{OUT} = -32 \text{ V}$	_	_	- 2	μΑ
Current	I <sub>LO3</sub>	Tri-state ports	V <sub>DD</sub> = 5.5 V, V <sub>OUT</sub> = 5.5 V / 0 V	_	_	2	
Output High Voltage	V <sub>OH2</sub>	Tri-state ports	$V_{DD} = 4.5 \text{ V}, I_{OH} = -0.7 \text{ mA}$	4.1	_	_	V
Output Low Voltage	V <sub>OL</sub>	Except XOUT	$V_{DD} = 4.5 \text{ V}, I_{OL} = 1.6 \text{ mA}$	_	_	0.4	V
	I <sub>OH1</sub>	P6, P7, P80, P81 port	V 45VV 24V	_	- 30	-	
Output High current	I <sub>OH2</sub>	P82 to P87, P9, PD, PE, PF ports	$V_{DD} = 4.5 \text{ V}, V_{OH} = 2.4 \text{ V}$	_	- 15	_	mA
Supply Current in NORMAL 1, 2			$V_{DD} = 5.5 \text{ V}$ $V_{IN} = 5.3 \text{ V} / 0.2 \text{ V}$	_	15	22	
modes Supply Current in IDLE 1, 2 modes			fc = 12.5 MHz fs = 32.768 kHz	_	6	12	mA
Supply Current in SLOW mode	l <sub>DD</sub>		V <sub>DD</sub> = 3.0 V	_	30	60	
Supply Current in SLEEP mode	1		$V_{IN} = 2.8 \text{ V} / 0.2 \text{ V}$ fs = 32.768 kHz	_	15	30	μΑ
Supply Current in STOP mode			V <sub>DD</sub> = 5.5 V V <sub>IN</sub> = 5.3 V / 0.2 V	-	0.5	10	ļ <sup>*</sup>

Note 1: Typical values show those at Topr =  $25^{\circ}$ C,  $V_{DD} = 5 V$ .

Note 2: Input Current  $I_{IN1,I_{IN3}}$ ; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.

**AD Conversion Characteristics** 

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Analog Reference Voltage	V <sub>AREF</sub>		4.5	_	V <sub>DD</sub>	
	V <sub>ASS</sub>		V <sub>SS</sub>		\ \	
Analog Reference Voltage Range	V <sub>AIN</sub>		V <sub>ASS</sub>	-	V <sub>AREF</sub>	V
Analog Input Voltage	I <sub>REF</sub>	$V_{AREF} = 5.5 \text{ V}, \ V_{ASS} = 0.0 \text{ V}$	_	0.5	1.0	mA
Nonlinearity Error		V <sub>DD</sub> = 5.0 V, V <sub>SS</sub> = 0.0 V	_	ı	± 1	
Zero Point Error		V <sub>AREF</sub> = 5.000 V	_	ı	± 1	
Full Scale Error		V <sub>ASS</sub> = 0.000 V	_	ı	± 1	LSB
Total Error		777	-	_	± 2	

Note: Quantizing error is not contained in those errors.

#### A.C. Characteristics

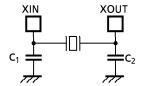
 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$ 

Parameter	Symbol	Conditions	Min	Тур.	Max	Unit
Machine Cycle Time		In NORMAL1, 2 modes	0.22	-	10	
	4	In IDLE1, 2 modes	0.32			
	tcy	In SLOW mode	447.6	-	133.3	μS
		In SLEEP mode	117.6			
High Level Clock Pulse Width	t <sub>WCH</sub>	For external clock operation	32			
Low Level Clock Pulse Width	t <sub>WCL</sub>	(XIN input), fc = 12.5 MHz	32	_	_	ns
High Level Clock Pulse Width	t <sub>WSH</sub>	For external clock operation	15.2	_	_	μS
Low Level Clock Pulse Width	t <sub>WSL</sub>	(XTIN input), fs = 32.768 kHz	13.2	_		$\mu$ 3

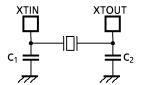
## Recommended Oscillating Conditions

$$(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$$

_		Oscillation			Recommended Constant		
Parameter Oscillator		Frequency	Recomm	ended Oscillator	C <sub>1</sub>	C <sub>2</sub>	
High-frequency Oscillation	Ceramic Resonator	12.5 MHz	Murata	CSA12.5MTZ	30 pF	30 pF	
	Ceramic Resonator	8 MHz	Murata	CSA8.00MTZ	30 pF	30 pF	
	Crystal Oscillator	12.5 MHz	NDK	AT-51	10 pF	10 pF	
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	NDK	MX-38T	15 pF	15 pF	



(1) High-frequency Oscillation



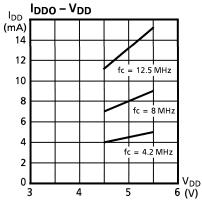
(2) Low-frequency Oscillation

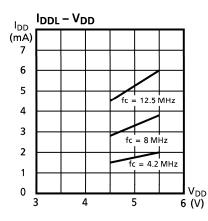
Note: An electrical shield by metal shied plate on the IC package should be recommend able in order to prevent the device from the high electric fieldstress applied for continuous reliable operation.

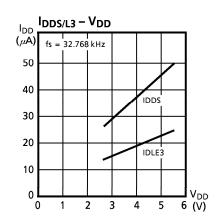
TOSHIBA

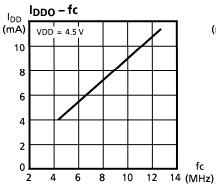
**Typical Characteristics** 

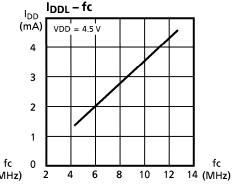
$$(Ta = 25^{\circ}C)$$

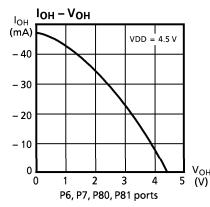


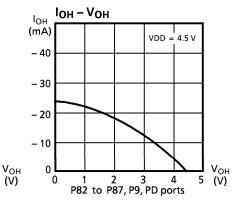


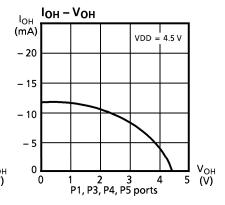


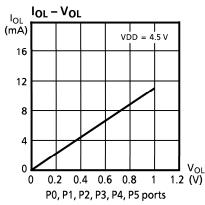










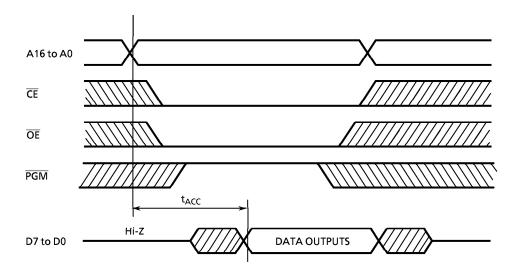


# D.C./A.C. Characteristics (PROM mode) $(V_{SS} = 0 V)$

## (1) Read Operation (VDD = $5.0 \pm 0.25 \text{ V}$ , Topr = $25 \pm 5^{\circ}\text{C}$ )

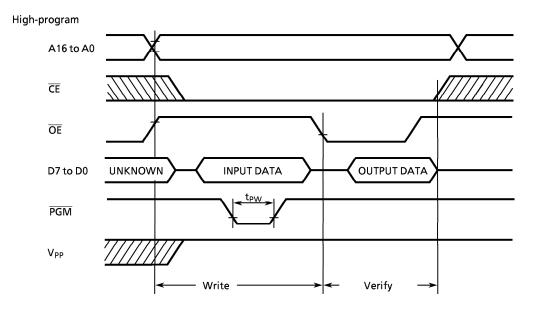
PARAMETER	SYMBOL	CONDITIONS	Min	Тур.	Max	UNIT
Input High Voltage (A0 to A16, CE, OE, PGM)	V <sub>IH4</sub>		VDD×0.7	-	VDD	>
Input Low Voltage (A0 to A16, CE, OE, PGM)	V <sub>IL4</sub>		0	-	0.8	V
Program Power Supply Voltage	V <sub>PP</sub>		4.75	5.0	5.25	٧
Address Access Time	t <sub>ACC</sub>		_	1.5 tcyc + 300	_	ns

Note: tcyc = 500 ns at 8 MHz



## (2) High-Speed Programming Operation (Topr = $25 \pm 5^{\circ}$ C, VDD = $6.25 \pm 0.25$ V)

PARAMETER	SYMBOL	CONDITIONS	Min	Тур.	Max	UNIT
Input High Voltage (D0 to D7, A0 to A16, CE, OE, PGM)	V <sub>IH4</sub>		VDD×0.7	-	VDD	٧
Input Low Voltage (D0 to D7, A0 to A16, CE, OE, PGM)	V <sub>IL4</sub>		0	-	0.8	V
Program Power Supply Voltage	$V_{PP}$		12.5	12.75	13.0	٧
Initial Program Pulse Width	t <sub>PW</sub>	V <sub>DD</sub> = 6.0 V	0.095	0.1	0.105	ms



Note 1: When  $V_{cc}$  power supply is turned on or after,  $V_{pp}$  must be increased. When  $V_{cc}$  power supply is turned off or before,  $V_{pp}$  must be decreased.

Note 2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage (12.75 V  $\pm$  0.5 V) to the  $V_{pp}$  pin as the device is damaged.

Note 3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.